

BD135 - BD136

BD139 - BD140

Complementary low voltage transistor

Features

- Products are pre-selected in DC current gain

Application

- General purpose

Description

These epitaxial planar transistors are mounted in the SOT-32 plastic package. They are designed for audio amplifiers and drivers utilizing complementary or quasi-complementary circuits. The NPN types are the BD135 and BD139, and the complementary PNP types are the BD136 and BD140.

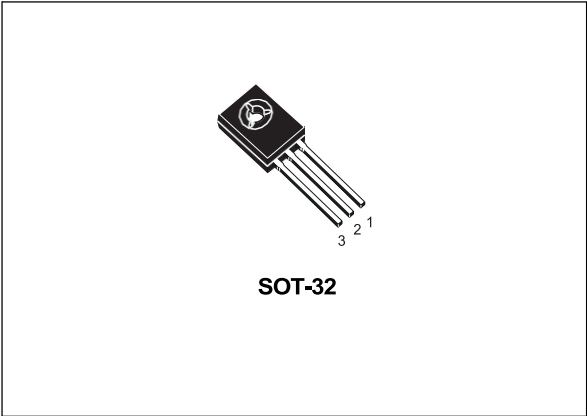
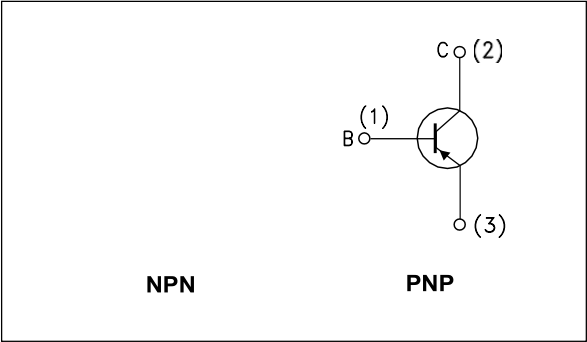


Figure 1. Internal schematic diagram



Order codes	Marking	Package	Packaging
BD135	BD135	SOT-32	Tube
BD135-16	BD135-16		
BD136	BD136		
BD136-16	BD136-16		
BD139	BD139		
BD139-10	BD139-10		
BD139-16	BD139-16		
BD140	BD140		
BD140-10	BD140-10		
BD140-16	BD140-16		

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Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value				Unit
		NPN		PNP		
		BD135	BD139	BD136	BD140	
V _{CBO}	Collector-base voltage (I _E = 0)	45	80	-45	-80	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	45	80	-45	-80	V
V _{EBO}	Emitter-base voltage (I _C = 0)	5		-5		V
I _C	Collector current	1.5		-1.5		A
I _{CM}	Collector peak current	3		-3		A
I _B	Base current	0.5		-0.5		A
P _{TOT}	Total dissipation at T _c ≤ 25 °C	12.5				W
P _{TOT}	Total dissipation at T _{amb} ≤ 25 °C	1.25				W
T _{stg}	Storage temperature	-65 to 150				°C
T _j	Max. operating junction temperature	150				°C

Table 3. Thermal data

Symbol	Parameter	Max value	Unit
$R_{thj-case}$	Thermal resistance junction-case	10	°C/W
$R_{thj-amb}$	Thermal resistance junction-ambient	100	°C/W

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Electrical characteristics

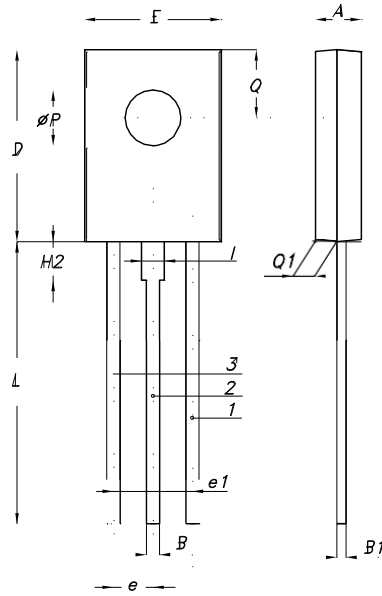
($T_{case} = 25\text{ °C}$ unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Polarity	Test conditions	Value			Unit
				Min.	Typ.	Max.	
I_{CBO}	Collector cut-off current ($I_E=0$)	NPN	$V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}, T_C = 125\text{ °C}$			0.1 10	μA μA
		PNP	$V_{CB} = -30\text{ V}$ $V_{CB} = -30\text{ V}, T_C = 125\text{ °C}$			-0.1 -10	μA μA
I_{EBO}	Emitter cut-off current ($I_C=0$)	NPN	$V_{EB} = 5\text{ V}$			10	μA
		PNP	$V_{EB} = -5\text{ V}$			-10	μA
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B=0$)	NPN	$I_C = 30\text{ mA}$ BD135 BD139	45 80			V V
		PNP	$I_C = -30\text{ mA}$ BD136 BD140	-45 -80			V V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	NPN	$I_C = 0.5\text{ A}, I_B = 0.05\text{ A}$			0.5	V
		PNP	$I_C = -0.5\text{ A}, I_B = -0.05\text{ A}$			-0.5	V
$V_{BE}^{(1)}$	Base-emitter voltage	NPN	$I_C = 0.5\text{ A}, V_{CE} = 2\text{ V}$			1	V
		PNP	$I_C = -0.5\text{ A}, V_{CE} = -2\text{ V}$			-1	V
$h_{FE}^{(1)}$	DC current gain	NPN	$I_C = 5\text{ mA}, V_{CE} = 2\text{ V}$	25			
			$I_C = 150\text{ mA}, V_{CE} = 2\text{ V}$	40		250	
			$I_C = 0.5\text{ A}, V_{CE} = 2\text{ V}$	25			
		PNP	$I_C = -5\text{ mA}, V_{CE} = -2\text{ V}$ $I_C = -150\text{ mA}, V_{CE} = -2\text{ V}$ $I_C = -0.5\text{ A}, V_{CE} = -2\text{ V}$	25 40 25		250	
$h_{FE}^{(1)}$	h_{FE} groups	NPN	$I_C = 150\text{ mA}, V_{CE} = 2\text{ V}$ BD139-10 BD135-16/BD139-16	63 100		160 250	
		PNP	$I_C = -150\text{ mA}, V_{CE} = -2\text{ V}$ BD140-10 BD136-16/BD140-16	63 100		160 250	

SOT-32 (TO-126) MECHANICAL DATA

DIM.	mm.		
	MIN.		AX.
	.4		2.9
			.88
B1	0.39		0.63
			1.05
	.4		7.8
			.54
e1	4.07	4.58	5.08
	.9		3.2
		.8	
Q1			.52
H2		2.15	
		.27	



1 = BASE
2 = COLLECTOR
3 = EMITTER

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